

DMTH10H003SPSW

100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	Ι _D Tc = +25°C	
1001/	$3m\Omega @ V_{GS} = 10V$	166A	
100V	$5m\Omega @ V_{GS} = 6V$	129A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

PowerDI5060-8 (SWP) (Type Q)

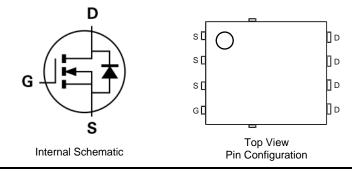
- Engine Management Systems
- **Body Control Electronics**
- DC-DC Converters

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208@3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Top View

Part Number	Backago	Packing		
	Package	Qty.	Carrier	
DMTH10H003SPSW-13	PowerDI5060-8 (SWP) (Type Q)	2,500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Pin1

Marking Information

Notes:



Bottom View

DII = Manufacturer's Marking H10H003SW = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 6)	Tc = +25°C Tc = +100°C	ID	166 117	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	664	А
Maximum Continuous Body Diode Forward Current (Note 6)		ls	166	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	664	А
Avalanche Current, L = 3mH		I _{AS}	20.2	А
Avalanche Energy, L = 3mH		E _{AS}	612	mJ

Thermal Characteristics

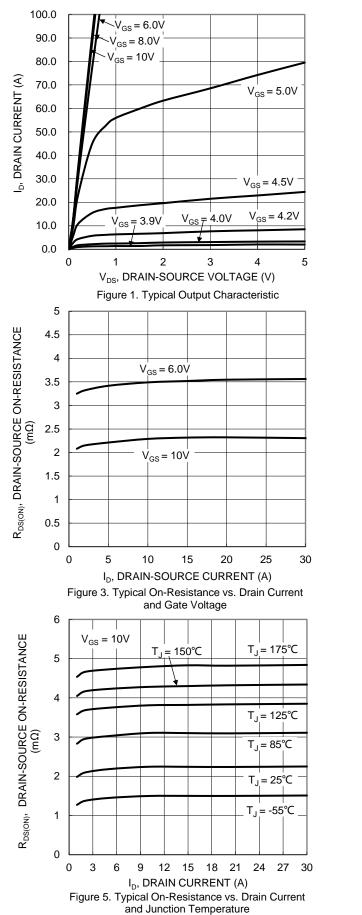
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	57	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	167	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	۵°

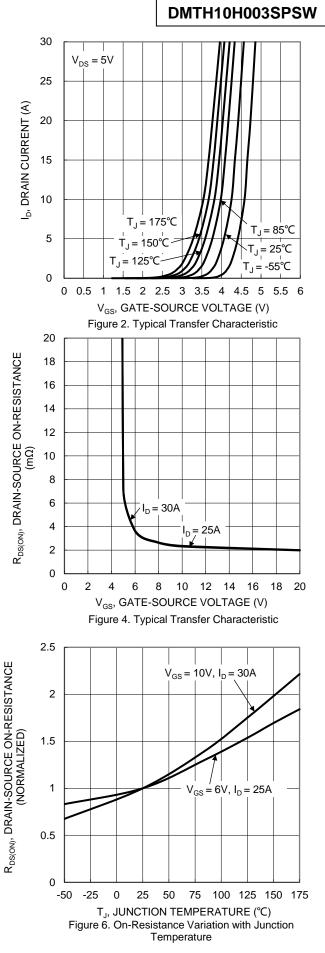
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	—	—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	2	2.6	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descer	—	2.2	3	mΩ	VGS = 10V, ID = 30A	
	RDS(ON)	_	3.4	5	mΩ	$V_{GS} = 6V, I_D = 25A$	
Diode Forward Voltage	Vsd	_	0.8	1.2	V	VGS = 0V, IS = 20A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss	_	5542	_	pF	$V_{DS} = 50V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss		1681	_			
Reverse Transfer Capacitance	Crss	—	34	—			
Gate Resistance	Rg	_	1.46	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	—	85.0	_		V _{DS} = 50V, I _D = 30A, V _{GS} = 10V	
Gate-Source Charge	Qgs	—	21.0	—	nC		
Gate-Drain Charge	Q _{gd}		19.7	_			
Turn-On Delay Time	t _{D(ON)}	—	16.0	—		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 30A, R_g = 3\Omega$	
Turn-On Rise Time	tR		23.2	_			
Turn-Off Delay Time	tD(OFF)	_	45.3	_	ns		
Turn-Off Fall Time	tF		29.6	—			
Body Diode Reverse Recovery Time	t _{RR}	_	71.7	_	ns	1= 204 di/dt 1004/uc	
Body Diode Reverse Recovery Charge	QRR	_	163.1	_	nC	IF = 30A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

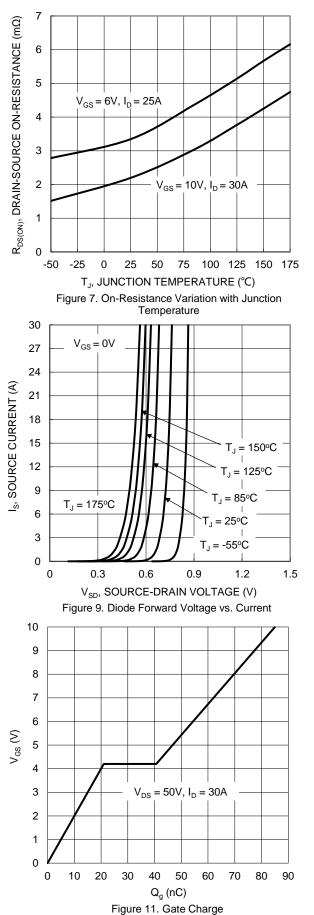


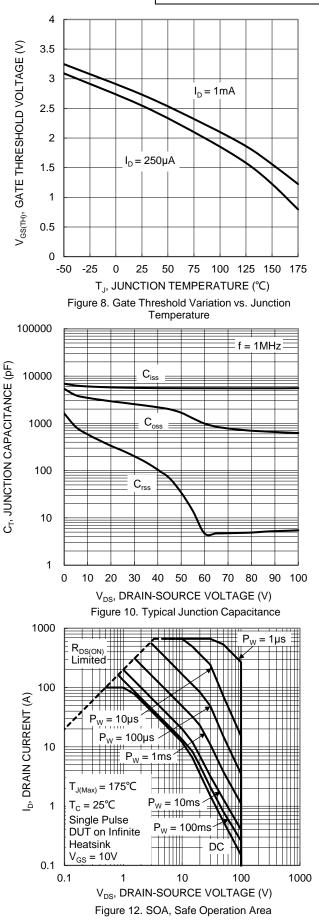








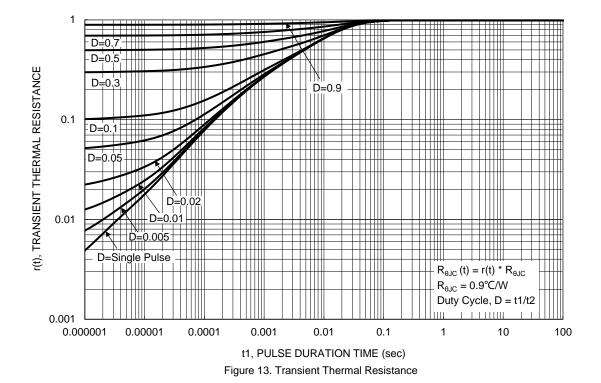




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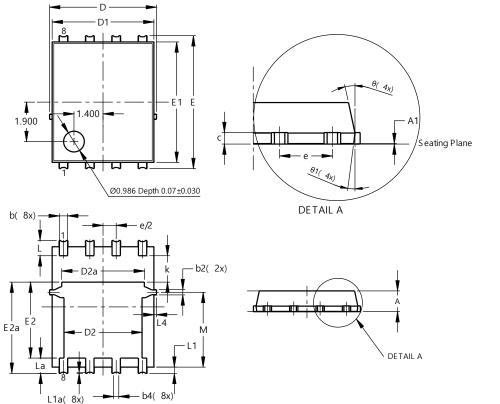


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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (SWP) (Type Q)

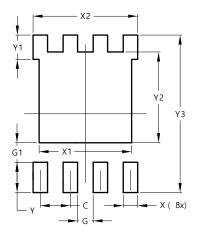
Dim Min Max Тур 0.90 1.10 1.00 Α A1 0 0.05 --<u>0.5</u>0 0.41 b 0.30 b2 0.20 0.35 0.25 b4 0.25REF 0.230 0.330 0.277 С D 5.15 BSC 5.10 3.96 D1 4.70 4.90 D2 3.56 3.76 D2a 3.78 4.18 3.98 Ε 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 е 1.27BSC 1.05 k L 0.635 0.835 0.735 La 0.635 0.835 0.735 0.200 0.400 0.300 L1 L1a 0.050RE L4 0.025 0.225 0.125 М 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7° All Dimensions in mm

PowerDI5060-8 (SWP) (Type Q)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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